

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,815,247 B2
DATED : November 9, 2004
INVENTOR(S) : Stalmans et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 11,

Line 21, after "reflector" please insert -- wherein the porous silicon layer formed comprises porous silicon parts and columnar conductive parts, said columnar conductive parts forming conductive connections between the substrate and a first region of a semiconductive region --.

Line 23, please delete "aid" and insert, therefor, -- said --.

Line 56, please delete "on" and insert, therefor, -- one --.

Line 63, after "and" please insert -- a --.

Column 12,

Line 5, please delete "at" and insert, therefor, -- that --.

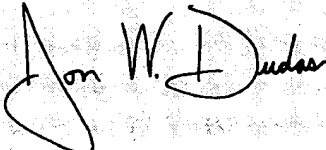
Line 23, please delete "si icon" and insert, therefor, -- silicon --.

Line 30, after "IV" please delete "or" and insert, therefor, -- and/or --.

Line 44, after "and" please insert -- a --.

Signed and Sealed this

Eighth Day of November, 2005

A handwritten signature in black ink, reading "Jon W. Dudas", is written over a rectangular grid background.

JON W. DUDAS

Director of the United States Patent and Trademark Office